

Low Voltage, Dual SPDT Analog Switch with Charge Pump

DESCRIPTION

The DG2616, DG2617, DG2618 are monolithic CMOS analog switching products designed for high performance switching of analog signals. Combining low power, high speed, low on-resistance and small physical size, the DG2616, DG2617, DG2618 are ideal for portable and battery powered applications.

The DG2616, DG2617, DG2618 have built-in charge-pump circuitry which lowers the minimum supply voltage to + 1.5 V while maintaining low on-resistance. The Control circuitry allows the DG2616, DG2617, DG2618 to operate in different configurations.

Built on Vishay Siliconix's low voltage process, the DG2616, DG2617, DG2618 has an epitaxial layer that prevents latch-up. Break-before-make is guaranteed.

The DG2616, DG2617, DG2618 are manufactured in space saving DFN-10 (3.0 x 3.0 mm). And as a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device terminations and is 100 % RoHS compliant.

FEATURES

- Low voltage operation (1.5 V to 3.6 V)
- Low on-resistance R_{ON}: 4.2 Ω typ. at 2.7 V
- Fast switching: t_{ON} = 39 ns t_{OFF} = 8 ns

DFN-10 package



ROHS COMPLIAN

BENEFITS

- Reduced power consumption
- High accuracy
- · Reduce board space
- TTL/1.8 V logic compatible
- · High bandwidth

APPLICATIONS

- · Cellular phones
- · Audio and video signal routing
- PCMCIA cards
- · Battery operated systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

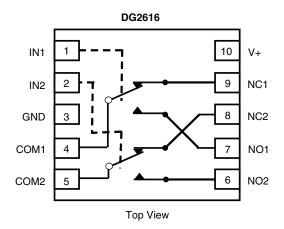
TRUTH TABLE DG2616							
Logic NC1, 2 NO1, 2							
0	ON	OFF					
1	OFF	ON					

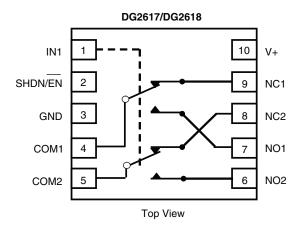
TRUTH TABLE DG2617								
SHDN/EN Logic IN Logic NC1, 2 NO1, 2 Charge Pur								
0	0	ON	OFF	ON				
0	1	OFF	ON	ON				
1	0	ON	OFF	OFF				
1	1	OFF	ON	OFF				

TRUTH TABLE DG2618								
SHDN/EN Logic IN Logic NC1, 2 NO1, 2 Charge Pu								
0	0	ON	OFF	ON				
0	1	OFF	ON	ON				
1	х	OFF	OFF	OFF				

ORDERING INFORMATION						
Temp. Range Package Part Number						
- 40 °C to 85 °C	DFN-10	DG2616DN-T1-E4 DG2617DN-T1-E4 DG2618DN-T1-E4				







ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted						
Parameter	neter Lir		Unit			
Reference to GND	V+	- 0.3 to 6.0	V			
Reference to GND	IN, COM, NC, NO ^a	- 0.3 to (V+ + 0.3)	7			
Current (Any terminal except NO, NC or 0	COM)	30				
Continuous Current (NO, NC, or COM)		± 150	mA			
Peak Current (Pulsed at 1 ms, 10 % Duty Cycle)		± 300				
Storage Temperature (D-Suffix)		- 65 to 150	°C			
Package Solder Reflow Conditions ^d						
Power Dissipation (Packages) ^b	DFN-10 ^c	1191	mW			

Notes

- a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 14.9 mW/°C above 70 °C
- d. Manual soldering with iron is not recommended for leadless components. The DFN-10 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.



		Test Conditions Otherwise Unless Specified		Limits - 40 °C to 85 °C			
Parameter	Symbol	$V+ = 3 V, \pm 10 \%, V_{IN} = 0.5 \text{ or } 1.4 V^{e}$	Temp.a	Min.b	Typ. ^c	Max.b	Unit
Analog Switch	,				, ,		
d	V _{NO} , V _{NC} ,		E. II	0			V
Analog Signal Range ^d	V _{COM}		Full	0		V+	V
		V+ = 1.5 V, V _{COM} = 1.5 V, I _{NO} , I _{NC} = 10 mA	Room Full		5.3	7.0 8.0	
		$V+ = 2.7 \text{ V}, V_{COM} = 1.5 \text{ V}, I_{NO}, I_{NC} = 10 \text{ mA}$	D		4.2	7.0	
On-Resistance	R _{ON}	$V+ = 2.7 \text{ V}, V_{COM} = 2.7 \text{ V}, I_{NO}, I_{NC} = 10 \text{ mA}$	Room		4.7	7.0	
			Full			8.0	
		$V + = 3.6 \text{ V}, V_{COM} = 3.6 \text{ V}, I_{NO}, I_{NC} = 10 \text{ mA}$	Room		5.5	7.0	0
		• 1 = 3.3 •, • COM = 3.3 •, • NO, • NC = 13 ·······	Full			8.0	Ω
R _{ON} Flatness ^d	R _{ON} Flatness	$V+ = 2.7 \text{ V}, V_{COM} = 1.5 \text{ V}, 2.7 \text{ V},$	Room		0.6	2.0	
R _{ON} Match ^d	ΔR_{ON}	I_{NO} , $I_{NC} = 10 \text{ mA}$	Room		0.1		
On Resistance (Shutdown)	R _{SHDN}	V+ = 3.6 V, V _{COM} = 1.7 V, I _{NO} , I _{NC} = 10 mA	Room Full		15	20 21	
	I _{NO(off)} ,		Room	- 2		2	
0.11.0%	I _{NC(off)}	$V+ = 3.6 V, V_{NO}, V_{NC} = 0.3 V/3.3 V,$	Full	- 10		10	
Switch Off Leakage Current	I _{COM(off)}	V _{COM} = 3.3 V/0.3 V	Room	- 2		2	nA
			Full	- 10		10	
Channel-On Leakage	I _{COM(on)}	$V + = 3.6 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 0.3 \text{ V}/3.3 \text{ V}$	Room	- 2		2	
Current	'COM(on)	1 = 3.3 t, tho, the = teom = 3.3 t/3.3 t	Full	- 10		10	
Digital Control							
Input High Voltage	V_{INH}	V+ = 1.5 V	-	1.0			
		V+ = 2.7 V to 3.6 V V+ = 1.5 V	Full	1.4		0.4	V
Input Low Voltage	V_{INL}	V+ = 1.5 V V+ = 2.7 V to 3.6 V	-			0.4	1
Input Capacitance	C _{in}	V1 = 2.7 V to 0.0 V	Full		3.2	0.0	pF
Input Current	I _{INL} or I _{INH}	V _{IN} = 0 or V+	Full	- 1		1	μΑ
Dynamic Characteristics	IIVE IIVIT						
			Room		39	69	
Turn-On Time	t _{ON}	V = 2.7 or 2.6 V V or V = 1.5 V	Full			76	
Turn-Off Time	torr	$V_{+} = 2.7 \text{ or } 3.6 \text{ V}, V_{NO} \text{ or } V_{NC} = 1.5 \text{ V},$	Room		9	39	ns
Turn-On Time	t _{OFF}	$R_L = 50 \Omega, C_L = 35 pF$	Full			41	
Break-Before-Make Time	t _d		Full	1			
Charge Injection ^d	Q_{INJ}	C_L = 1 nF, V_{GEN} = 0 V, R_{GEN} = 0 Ω	Room		7		рC
,		$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$			- 77		
Off-Isolation ^d	OIRR	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 100 MHz$	Room		- 32		dB
Crosstalk ^{d, f}		$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$	HOOM		- 80		uL
	X _{TALK}	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 100 MHz$			- 32		
N N Off Consoiteneed	C _{NO(off)}		Room		9		
N _O , N _C Off Capacitance ^d	C _{NC(off)}	f _ 1 MI I=	Room		7		~r
Observed C	C _{NO(on)}	f = 1 MHz	Room		21		pF
Channel-On Capacitance ^d	C _{NC(on)}		Room		19		

DG2616, DG2617, DG2618

Vishay Siliconix



SPECIFICATIONS V+ = 3 V									
Test Conditions Otherwise Unless Specified				Limits - 40 °C to 85 °C					
Parameter	arameter Symbol V+ = 3 V, \pm 10 %, V_{IN} = 0.5 or 1.4 V^{e}				Typ.c	Max.b	Unit		
Power Supply									
Power Supply Range	V+			1.5		3.6	V		
Power Supply Current	l+	$V+ = 3.6 \text{ V}, V_{IN} = 0 \text{ or } V+, \text{SHDN/}\overline{\text{EN}} = 0 \text{ V}$	Full		104	300	μΑ		
I ower Supply Current	i+	$V+ = 3.6 \text{ V}, V_{IN} = 0 \text{ or } V+, \text{SHDN/}\overline{\text{EN}} = V+$	i uli		0.1	2	μΑ		

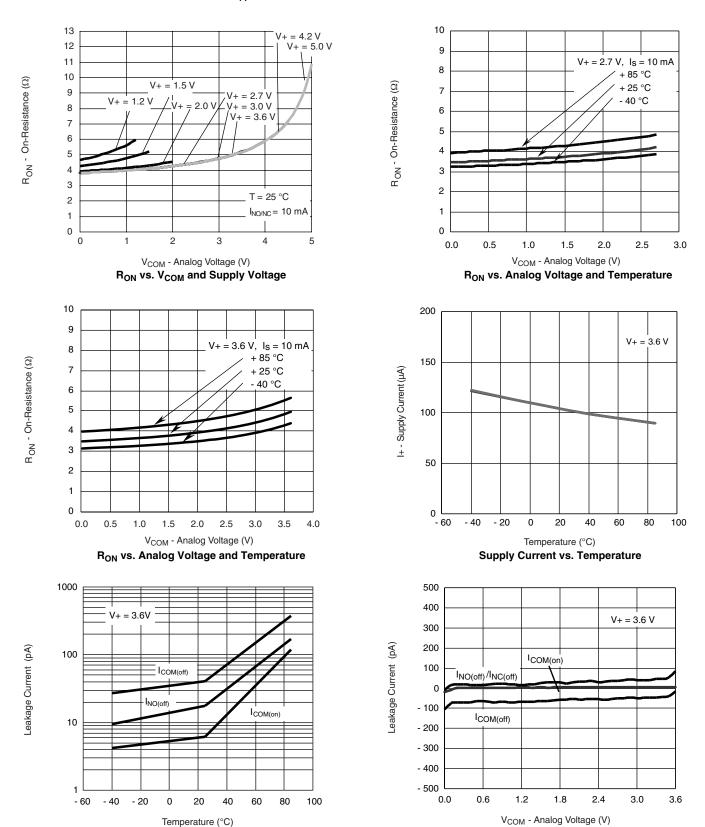
Notes:

- a. Room = 25 $^{\circ}$ C, Full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, not subjected to production test.
- e. V_{IN} = input voltage to perform proper function.
- f. Crosstalk measured between channels.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS $T_A = 25$ °C, unless otherwise noted



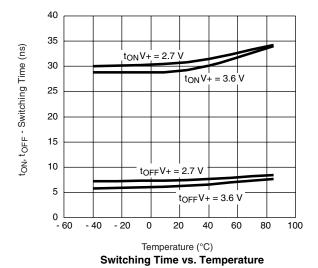
Document Number: 74411 S-82149-Rev. B, 08-Sep-08

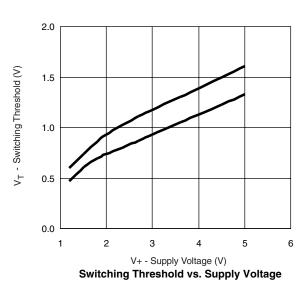
Leakage Current vs. Temperature

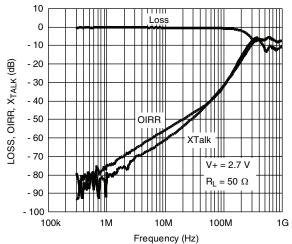
Leakage vs. Analog Voltage

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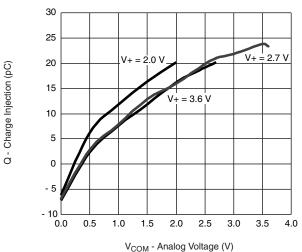
TYPICAL CHARACTERISTICS $T_A = 25$ °C, unless otherwise noted







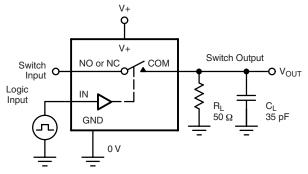
Insertion Loss, Off-Isolation Crosstalk vs. Frequency



Charge Injection vs. Analog Voltage



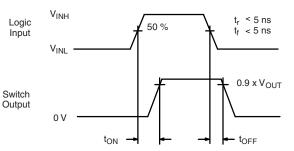
TEST CIRCUITS



C_L (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$

C_L (includes fixture and stray capacitance)



Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

Figure 1. Switching Time

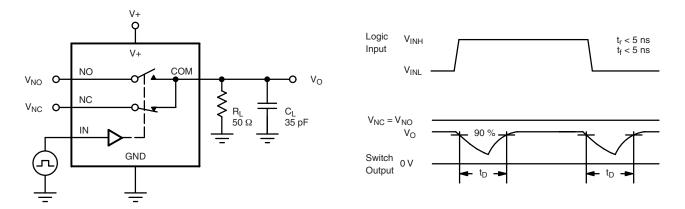


Figure 2. Break-Before-Make Interval

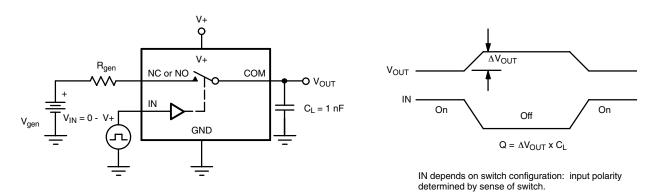


Figure 3. Charge Injection

TEST CIRCUITS



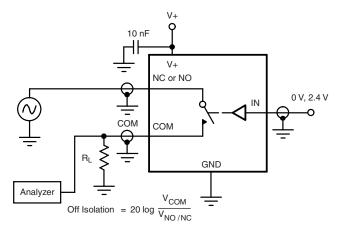


Figure 4. Off-Isolation

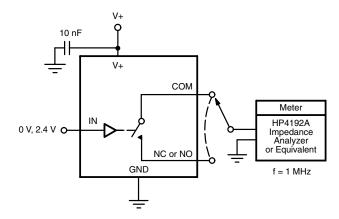
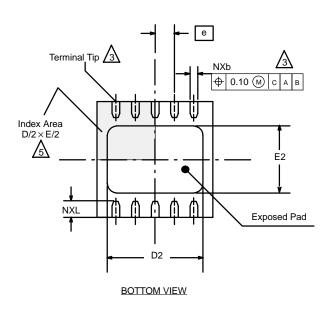


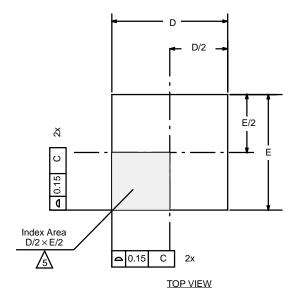
Figure 5. Channel Off/On Capacitance

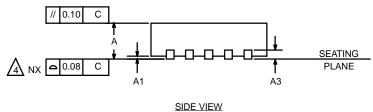
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DFN-10 LEAD (3 X 3)







NOTES:

1. All dimensions are in millimeters and inches.

N is the total number of terminals.

Dimension b applies to metallized terminal and is measured between 0.15 and 0.30 mm from terminal tip. $\,$



Coplanarity applies to the exposed heat sink slug as well as the



The pin #1 identifier may be either a mold or marked feature, it must be located within the zone iindicated.

	МІ	MILLIMETERS			INCHES			
Dim	Min	Nom	Max	Min	Nom	Max		
Α	0.80	0.90	1.00	0.031	0.035	0.039		
A1	0.00	0.02	0.05	0.000	0.001	0.002		
А3		0.20 BSC			0.008 BSC			
b	0.18	0.23	0.30	0.007 0.009 0.012				
D		3.00 BSC			0.118 BSC			
D2	2.20	2.38	2.48	0.087 0.094 0.09				
Е	3.00 BSC				0.118 BSC			
E2	1.49	1.64	1.74	0.059	0.065	0.069		
е		0.50 BSC		0.020 BSC				
L	0.30	0.40	0.50	0.012	0.016	0.020		
*Use millimeters as the primary measurement.								
ECN: S-42	2134—Rev. A	, 29-Nov-04						

DWG: 5943

Document Number: 73181 www.vishay.com 29-Nov-04



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